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**Time-Resolved Spectroscopy of Energy Transfers in Optoelectronic Media**

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# Contents

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<b>Symbols and Abbreviations</b>	<b>vii</b>
<b>Introduction</b>	<b>1</b>
0.1 Semiconductors. Silicon . . . . .	2
0.2 Optical doping . . . . .	3
0.2.1 Rare earth ions . . . . .	4
0.2.2 Silicon nanocrystals . . . . .	5
<b>1 Si/Si:Er multilayers</b>	<b>7</b>
1.1 Donor-state enabling Er-related luminescence in silicon . . . . .	8
1.1.1 Introduction . . . . .	8
1.1.2 Experiment . . . . .	9
1.1.3 Results and Discussion . . . . .	10
1.1.4 Conclusions . . . . .	16
1.2 Electro-optical memory effect for 1.5 $\mu\text{m}$ photonics . . . . .	17
1.2.1 Introduction . . . . .	17
1.2.2 Preliminaries . . . . .	18
1.2.3 Results . . . . .	19
1.2.4 Discussion . . . . .	22
1.2.5 Conclusions . . . . .	25
<b>2 Sensitization of Er<sup>3+</sup> with silicon nanocrystals in a SiO<sub>2</sub> matrix</b>	<b>27</b>
2.1 Nanoseconds dynamics of the 1.5 $\mu\text{m}$ Er-related photoluminescence	31
2.1.1 Introduction . . . . .	31
2.1.2 Results . . . . .	31
2.1.3 Discussion . . . . .	33
2.2 Energy transfer processes between Si NCs and Er <sup>3+</sup> . . . . .	39
2.2.1 Introduction . . . . .	39

2.2.2	Results . . . . .	40
2.2.3	Theory . . . . .	47
2.2.4	Discussion . . . . .	54
2.2.5	Conclusions . . . . .	61
2.3	Space-separated quantum cutting . . . . .	62
2.3.1	Introduction . . . . .	62
2.3.2	Results . . . . .	63
2.3.3	Discussion . . . . .	67
2.3.4	Conclusions . . . . .	70
<b>3</b>	<b>Er-doped large band gap hosts</b>	<b>71</b>
3.1	Photoluminescence and excitation spectroscopy of Er <sup>3+</sup> in GaN . . . . .	71
3.1.1	Results . . . . .	71
3.1.2	Discussion . . . . .	74
3.2	On 2.7 μm emission from Er-doped large band gap hosts . . . . .	77
3.2.1	Introduction . . . . .	77
3.2.2	Experimental details . . . . .	78
3.2.3	Results and discussion . . . . .	78
3.2.4	Conclusions . . . . .	82
<b>A</b>	<b>Calculations of energy exchange between Si NCs and Er<sup>3+</sup> ions</b>	<b>83</b>
A.1	Excitation due to intra-band transition . . . . .	84
A.2	Erbium excitation by the recombination of confined carriers . . . . .	89
A.3	Dipole-dipole contribution . . . . .	91
<b>B</b>	<b>The relative quantum efficiency</b>	<b>93</b>
	<b>Bibliography</b>	<b>97</b>
	<b>Summary</b>	<b>103</b>
	<b>Samenvatting</b>	<b>107</b>
	<b>Acknowledgements</b>	<b>111</b>